TPS61253A, TPS61253E, TPS61253F 3.8MHz, 5V, 4A Boost Converter in 1.2mm x 1.3mm WCSP

1 Features

- Wide input voltage range from 2.3V to 5.5V (TPS61253A, TPS61253F)
- Wide input voltage range from 2.5V to 5.5V (Startup>2.6V, TPS61253E)
- Fixed output voltage: 4.5 / 4.7 / 5.0 / 5.2V / 5.25V
- Two FETs integrated: 35mΩ LS-FET, 60mΩ HS-FET
- IOUT ≥ 1500mA continuously at VOUT = 5V and VIN ≥ 3V (TPS61253A, TPS61253F)
- IOUT ≥ 1500mA continuously at VOUT = 5.25V and VIN ≥ 3V (TPS61253E)
- 42µA quiescent current from input
- 4A switching valley current limit (TPS61253A)
- 4.5A switching valley current limit (TPS61253E, TPS61253F)
- TPS61253E and TPS61253F support 1.2V I/O
- TPS612532A output discharge function available
- 3.8MHz switching frequency
- Selectable Auto PFM, Forced PWM, and Ultrasonic mode
- Support pass-through mode
- ±2% output voltage accuracy
- 600µs soft-start time
- Hiccup-mode short protection
- Load disconnection during shutdown
- Thermal shutdown
- Create a custom design using the TPS61253A with the WEBENCH® Power Designer

2 Applications

- Smart phones
- Portable speaker
- USB charging ports
- NFC PA supply
- Li battery to 5V power conversion

3 Description

The TPS61253x device provides a power supply solution for battery-powered portable applications. With the input voltage ranging from 2.3V to 5.5V (TPS61253A, TPS61253F) or 2.5V to 5.5V (TPS61253E), the device supports the applications powered by the Li-Ion batteries with the extended voltage range. Different fixed output voltage versions are available of 4.5V, 4.7V, 5V, 5.2V and 5.25V. The TPS61253x supports up to 1500mA load current from a battery discharged as low as 3V.

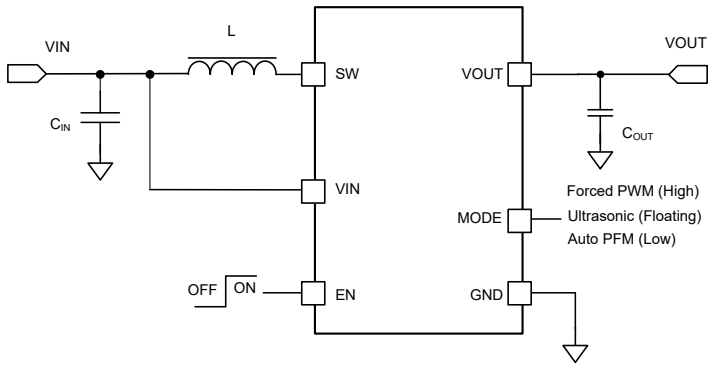
The TPS61253x operates at typical 3.8MHz switching frequency. The TPS61253x can be flexibly configured at the Auto PFM mode, forced PWM mode, or ultrasonic mode. The Auto PFM mode can benefit with the high efficiency at the light load. The forced PWM operation can make the switching frequency be constant crossing the whole load range. The ultrasonic mode keeps the switching frequency always larger than 25kHz at any load condition to avoid the acoustic noise.

TPS61253x has a built-in 600µs soft start to avoid the inrush current at start-up. When the output is shorted, the device enters into the hiccup mode and recovers automatically after the short releases. During the shutdown, the load is completely disconnected from the input end with maximum 1.3µA current being consumed.

Device Information

PART NUMBER	PACKAGE(1)	BODY SIZE (NOM)
TPS61253x	DSBGA (9)	1.2mm × 1.3mm

(1) For all available packages, see the orderable addendum at the end of the data sheet.



Typical Schematic

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4 Device Comparison

PART NUMBER	OUTPUT VOLTAGE	SW VALLEY CURRENT LIMIT (TYP.)	DC START-UP CURRENT LIMT (TYP.)	INPUT START-UP VOLTGAE	EN I/O LOGIC	SPECIFIC FEATURES
TPS61253A	5V	4A	1.5A	2.3V	Supports 1.8V logic I/O	Supports output 5V, up to 1500mA
TPS612532A	5V	4A	1.5A	2.3V	Supports 1.8V logic I/O	Supports output 5V, up to 1500mA with output discharge function
TPS61253E	5.25V	4.5A	1.5A	2.6V	Supports both 1.8V and 1.2V logic I/O	Supports output 5.25V, up to 1500mA
TPS61253F	5V	4.5A	1.5A	2.3V	Supports both 1.8V and 1.2V logic I/O	Supports output 5V, up to 1500mA
TPS61254A(1)	4.5V	2.5A	0.75A	2.3V	Supports 1.8V logic I/O	Supports output 4.5V, up to 1000mA
TPS61255A(1)	4.7V	4A	1.5A	2.3V	Supports 1.8V logic I/O	Supports output 4.5V, up to 1500mA
TPS612561A(1)	5V	2.5A	0.75A	2.3V	Supports 1.8V logic I/O	Supports output 5V, up to 1000mA
TPS61258A(1)	4.5V	4A	1.5A	2.3V	Supports 1.8V logic I/O	Supports output 4.5V, up to 1500mA
TPS612592A(1)	5.2V	4A	0.75A	2.3V	Supports 1.8V logic I/O	Supports output 5.2V, up to 1500mA
TPS612531A(1)	5V	4A	1.5A	2.3V	Supports 1.8V logic I/O	Supports output 5V, up to 1500mA with PFM/PWM mode only

(1) Preview. Contact TI factory for more information.

5 Pin Configuration and Functions

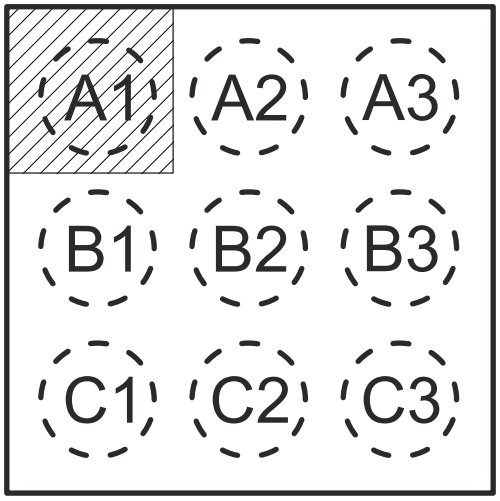


Figure 5-1. 9-Pin DSBGA YFF Package (Top View)

Table 5-1. Pin Functions

PIN		I/O	DESCRIPTION
NAME	NO.		
EN	B3	I	This is the enable pin of the device. Connecting this pin to ground forces the device into shutdown mode. Pulling this pin high enables the device. There is an internal resistor pulled to GND.
GND	C1, C2	–	Ground pin
MODE	C3	–	Operation mode selection pin Mode = Low, the device works in the Auto PFM mode with good light load efficiency. Mode = High, the device is in the forced PWM mode, keep the switching frequency be constant crossing the whole load range. Mode = Floating, the device works in the ultrasonic mode; it keeps the switching frequency larger than 25kHz to avoid the acoustic frequency toward no load condition.
SW	B1, B2	I/O	The switch pin of the converter. It is connected to the drain of the internal low-side power FET and the source of the internal high-side power FET.
VIN	A3	I	Power supply input
VOUT	A1, A2	O	Boost converter output

6 Specifications

6.1 Absolute Maximum Ratings

Over operating free-air temperature range (unless otherwise noted)(1)

		MIN	MAX	UNIT
Voltage range at terminals	Voltage at VIN, EN, MODE, VOUT	–0.3	6	V
	Voltage at SW	–0.3	7	V
Storage temperature, T_{stg}		-65	150	°C

(1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

6.2 ESD Ratings

			VALUE	UNIT
$V_{(ESD)}$	Electrostatic discharge	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001(1)	±2000	V
		Charged-device model (CDM), per JEDEC specification JESD22C101(2)	±500	

(1) JEDEC document JEP155 states that 500V HBM allows safe manufacturing with a standard ESD control process. Manufacturing with less than 500V HBM is possible with the necessary precautions.
(2) JEDEC document JEP157 states that 250V CDM allows safe manufacturing with a standard ESD control process. Manufacturing with less than 250V CDM is possible with the necessary precautions.

6.3 Recommended Operating Conditions

Over operating free-air temperature range unless otherwise noted.

		MIN	NOM	MAX	UNIT
V_{IN}	Input voltage (TPS61253A, TPS61253F)	2.3		5.5	V
	Input voltage (TPS61253E)	2.5		5.5	V
L	Effective inductance	0.33		1.3	µH
C_{OUT}	Effective output capacitance	3.5	5	30	µF
T_J	Operating junction temperature	–40		125	ºC

6.4 Thermal Information

THERMAL METRIC(1)		TPS61253x YFF (DSBGA) 9 PINS	UNIT
$R_{\theta JA}$	Junction-to-ambient thermal resistance	108.3	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	1.2	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	28.8	°C/W
ψ_{JT}	Junction-to-top characterization parameter	0.6	°C/W
ψ_{JB}	Junction-to-board characterization parameter	28.9	°C/W

(1) For more information about traditional and new thermal metrics, see the *Semiconductor and IC Package Thermal Metrics* application report, SPRA953.

6.5 Electrical Characteristics

For TPS61253A and TPS61253F, V_{IN} = 2.3V to 4.85V , V_{OUT} = 5V , T_J = –40°C to 125°C ; Typical values are at V_{IN} = 3.6V , T_J = 25°C, unless otherwise noted.

For TPS61253E, V_{IN} = 2.6V to 4.85V , V_{OUT} = 5.25V , T_J = –40°C to 125°C ; Typical values are at V_{IN} = 3.6V , T_J = 25°C, unless otherwise noted.

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
SUPPLY CURRENT						
V_{IN_UVLO}	Input voltage under voltage lockout (UVLO) threshold	V_{IN} rising, TPS61253A, TPS61253F		2.2	2.3	V
		V_{IN} falling, TPS61253A, TPS61253F		2.1	2.2	V
	Input voltage under voltage lockout (UVLO) threshold (E version)	V_{IN} rising, TPS61253E	2.4	2.5	2.6	V
		V_{IN} falling, TPS61253E	2.3	2.4	2.5	V
I_Q	Quiescent current into VIN pin	V_{IN} = 3.6V, V_{OUT} = 5V , EN = V_{IN} Device not switching		42	50	µA
	Quiescent current into VOUT pin	V_{IN} = 3.6V, V_{OUT} = 5V , EN = V_{IN} Device not switching		6.6	12	µA
I_{SD}	Shutdown current	EN = GND , V_{IN} = 2.3V to 5.5V, –40°C ≤ T_J ≤ 85°C		0.05	1.3	µA
OUTPUT VOLTAGE						
V_{OUT}	PWM Operation	2.3V ≤ V_{IN} ≤ 4.85V, I_{OUT} = 0mA, PWM operation. Open Loop. TPS61253A, TPS61253F	4.9	5	5.1	V
	PWM Operation	2.6V ≤ V_{IN} ≤ 4.85V, I_{OUT} = 0mA, PWM operation. Open Loop. TPS61253E	5.145	5.25	5.355	V
	PFM Operation	Auto PFM Mode		100.8		%V_{OUT}
	Ultrasonic Operation	Ultrasonic Mode		101.6		%V_{OUT}
R_{DIS}	output discharge resistor	VOUT = 5V, TPS612532A		350		Ω
POWER SWITCHES						
R_{DSON}	Low-side FET on resistance			35	55	mΩ
	High-side FET on resistance			60	80	mΩ
CURRENT LIMIT						
I_{LIM_SW}	Switching valley current limit at Auto PFM / Ultrasonic Mode	TPS61253A	3.4	4	4.6	A
	Switching valley current limit at Forced PWM Mode	TPS61253A	3.35	3.95	4.55	A
	Switching valley current limit at Auto PFM / Ultrasonic Mode	TPS61253E, TPS61253F	3.9	4.5	5.1	A
	Switching valley current limit at Forced PWM Mode	TPS61253E, TPS61253F	3.85	4.45	5.05	A
I_{LIM_DC}	DC startup current limit	TPS61253A, TPS61253E, TPS61253F	1	1.5		A
EN AND MODE LOGIC						
V_{EN_H}	EN logic high threshold	TPS61253A			1.2	V
		TPS61253E, TPS61253F			0.9	V
V_{EN_L}	EN logic low threshold	TPS61253A	0.4			V
		TPS61253E, TPS61253F	0.36			V
R_{EN}	EN pull-down resistor			930		kΩ
V_{MODE_H}	Mode logic high threshold				1.2	V
V_{MODE_L}	Mode logic low threshold		0.4			V
V_{MODE_F}	Mode pin floating voltage		0.75	0.8	0.85	V

6.5 Electrical Characteristics (continued)

For TPS61253A and TPS61253F, V_{IN} = 2.3V to 4.85V , V_{OUT} = 5V , T_J = –40°C to 125°C ; Typical values are at V_{IN} = 3.6V , T_J = 25°C, unless otherwise noted.

For TPS61253E, V_{IN} = 2.6V to 4.85V , V_{OUT} = 5.25V , T_J = –40°C to 125°C ; Typical values are at V_{IN} = 3.6V , T_J = 25°C, unless otherwise noted.

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
I_{MODE_UP}	Pull up current			1		µA
I_{MODE_DOWN}	Pull down current			1		µA
PROTECTION						
T_{SD_R}	Thermal shutdown rising threshold			150		ºC
T_{SD_HYS}	Thermal protection hysteresis			20		ºC

6.6 Timing Requirements

For TPS61253A and TPS61253F, V_{IN} = 2.3V to 4.85V , V_{OUT} = 5V , T_J = –40°C to 125°C ; Typical values are at V_{IN} = 3.6V , T_J = 25°C, unless otherwise noted.

For TPS61253E, V_{IN} = 2.6V to 4.85V , V_{OUT} = 5.25V , T_J = –40°C to 125°C ; Typical values are at V_{IN} = 3.6V , T_J = 25°C, unless otherwise noted.

			MIN	NOM	MAX	UNIT
HICCUP OFF TIME						
t_{HCP_ON}	Hiccup on time	V_{IN} = 3.6V		1000		µs
t_{HCP_OFF}	Waiting time for the restart	V_{IN} = 3.6V		20		ms
START UP TIME						
t_{EN_DELAY}	Startup delay time	Time from EN high to start switching, No load		70		µs
t_{SS}	Soft start time	Time from EN high to V_{OUT}, No load		600		µs

6.7 Switching Characteristics

For TPS61253A and TPS61253F, V_{IN} = 2.3V to 4.85V , V_{OUT} = 5V , T_J = –40°C to 125°C ; Typical values are at V_{IN} = 3.6V , T_J = 25°C, unless otherwise noted.

For TPS61253E, V_{IN} = 2.6V to 4.85V , V_{OUT} = 5.25V , T_J = –40°C to 125°C ; Typical values are at V_{IN} = 3.6V , T_J = 25°C, unless otherwise noted.

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
f_{SW}	Switching frequency, PWM mode	V_{IN} = 3.6V		3800		kHz
	Switching frequency, Ultrasonic mode	V_{IN} = 3.6V	25			kHz

6.8 Typical Characteristics

This section is based on the test results of TPS61253A, unless otherwise noted.

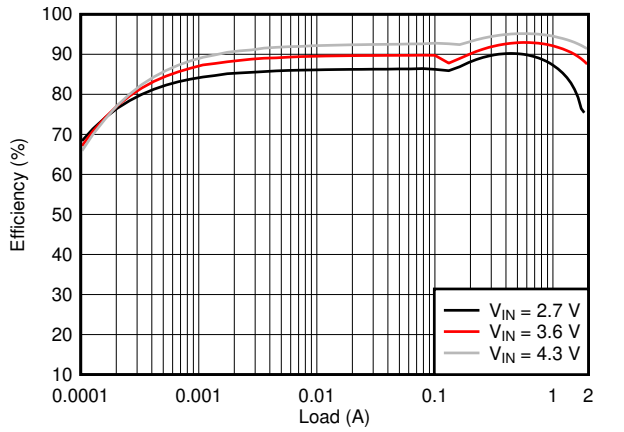


Figure 6-1. Efficiency vs Load

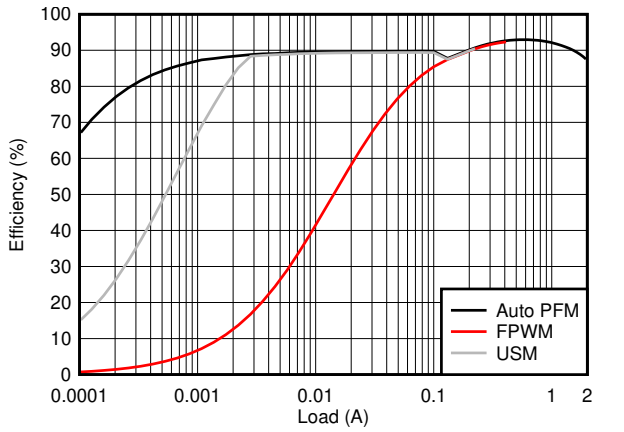


Figure 6-2. Efficiency vs Load

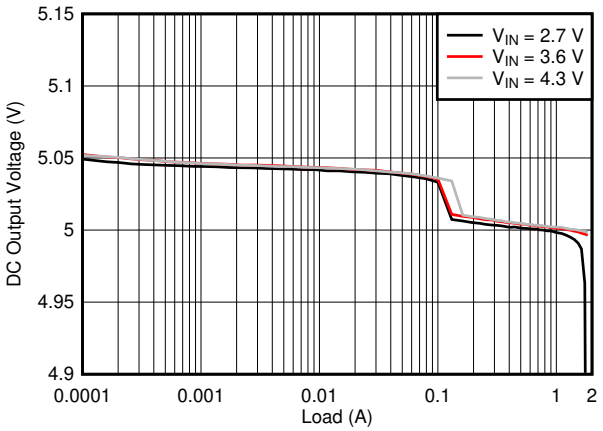


Figure 6-3. DC Output Voltage vs Load

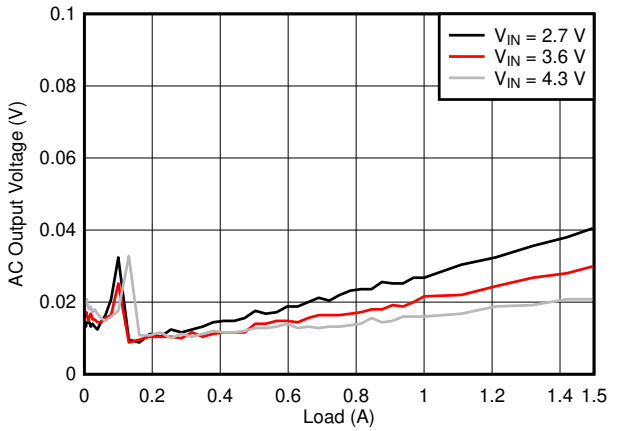


Figure 6-4. AC Output Voltage vs Load

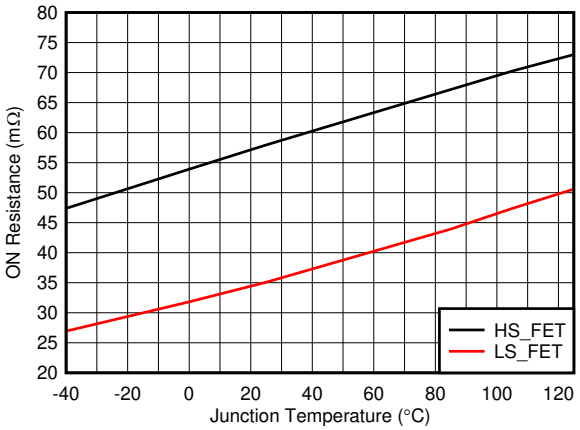


Figure 6-5. $RDS_{(ON)}$ vs Temperature

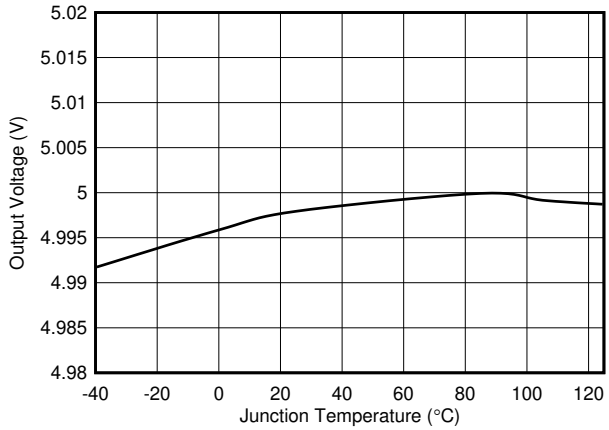


Figure 6-6. V_{OUT} vs Temperature

6.8 Typical Characteristics (continued)

This section is based on the test results of TPS61253A, unless otherwise noted.

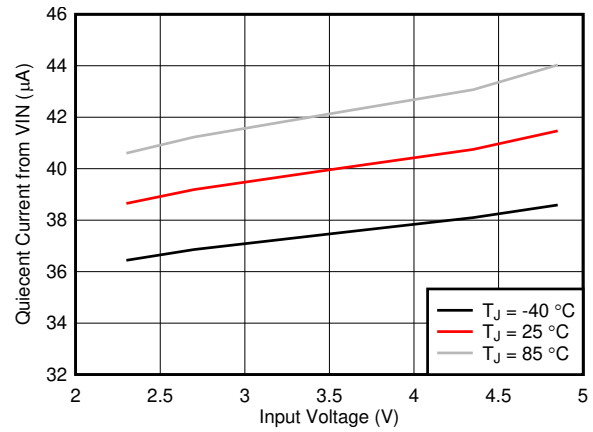


Figure 6-7. Quiescent Current (from VIN) vs Input Voltage

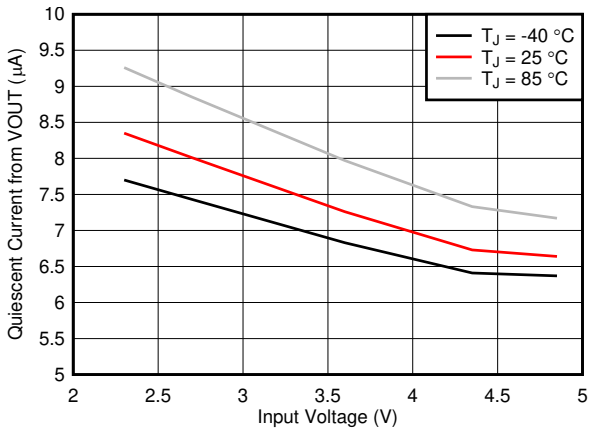


Figure 6-8. Quiescent Current (from VOUT) vs Input Voltage

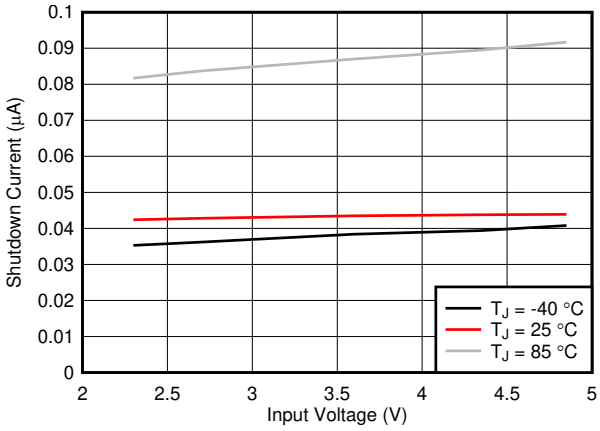


Figure 6-9. Shutdown Current vs Input Voltage

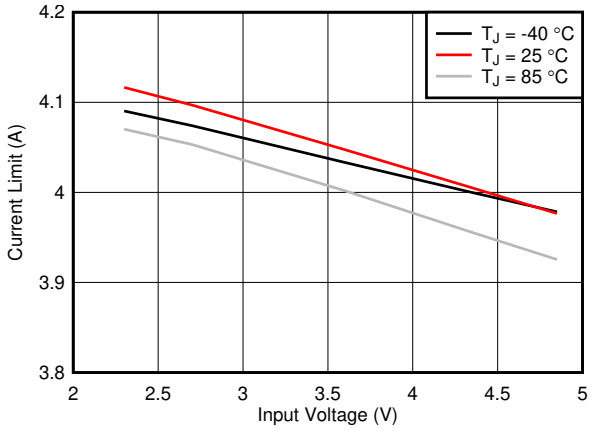


Figure 6-10. Current Limit (Auto PFM) vs Input Voltage

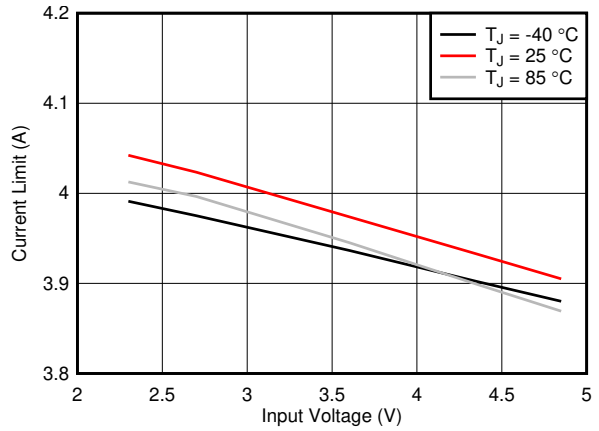


Figure 6-11. Current Limit (Forced PWM) vs Input Voltage

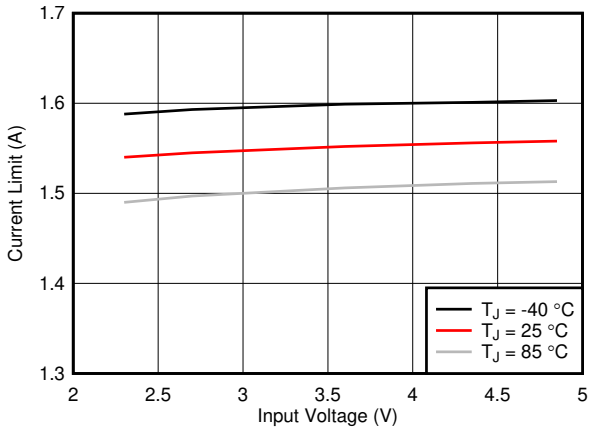


Figure 6-12. DC Startup Current Limit vs Input Voltage

6.8 Typical Characteristics (continued)

This section is based on the test results of TPS61253A, unless otherwise noted.

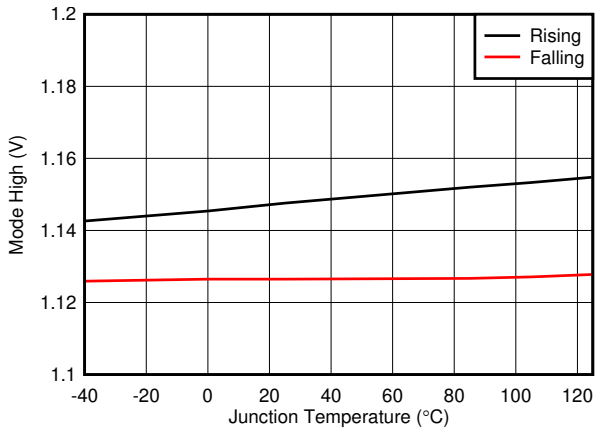


Figure 6-13. Mode High Rising / Falling vs Temperature

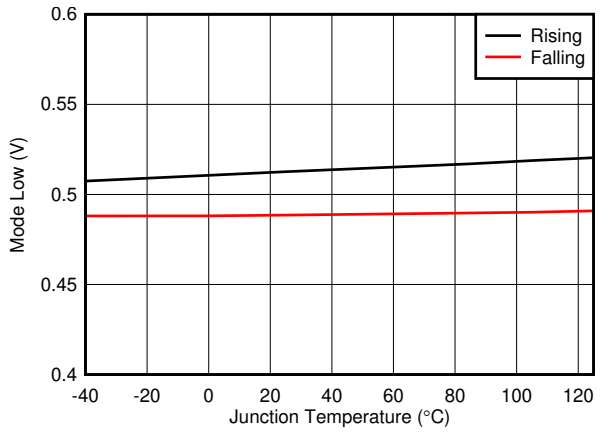


Figure 6-14. Mode Low Rising / Falling vs Temperature

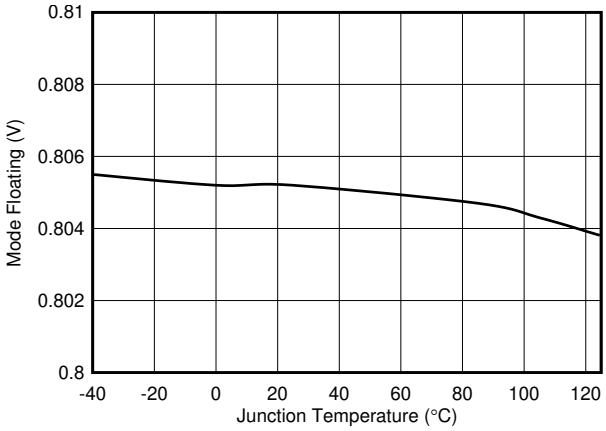


Figure 6-15. Mode Floating vs Temperature

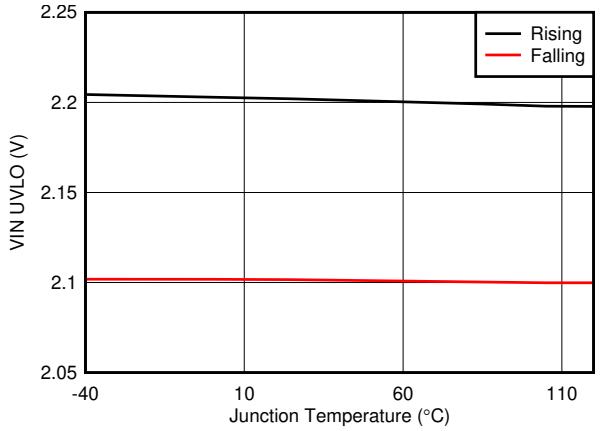


Figure 6-16. VIN UVLO vs Temperature

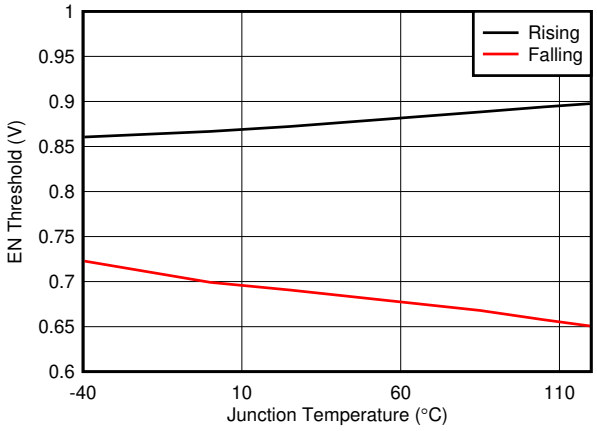


Figure 6-17. EN Threshold vs Temperature

7 Detailed Description

7.1 Overview

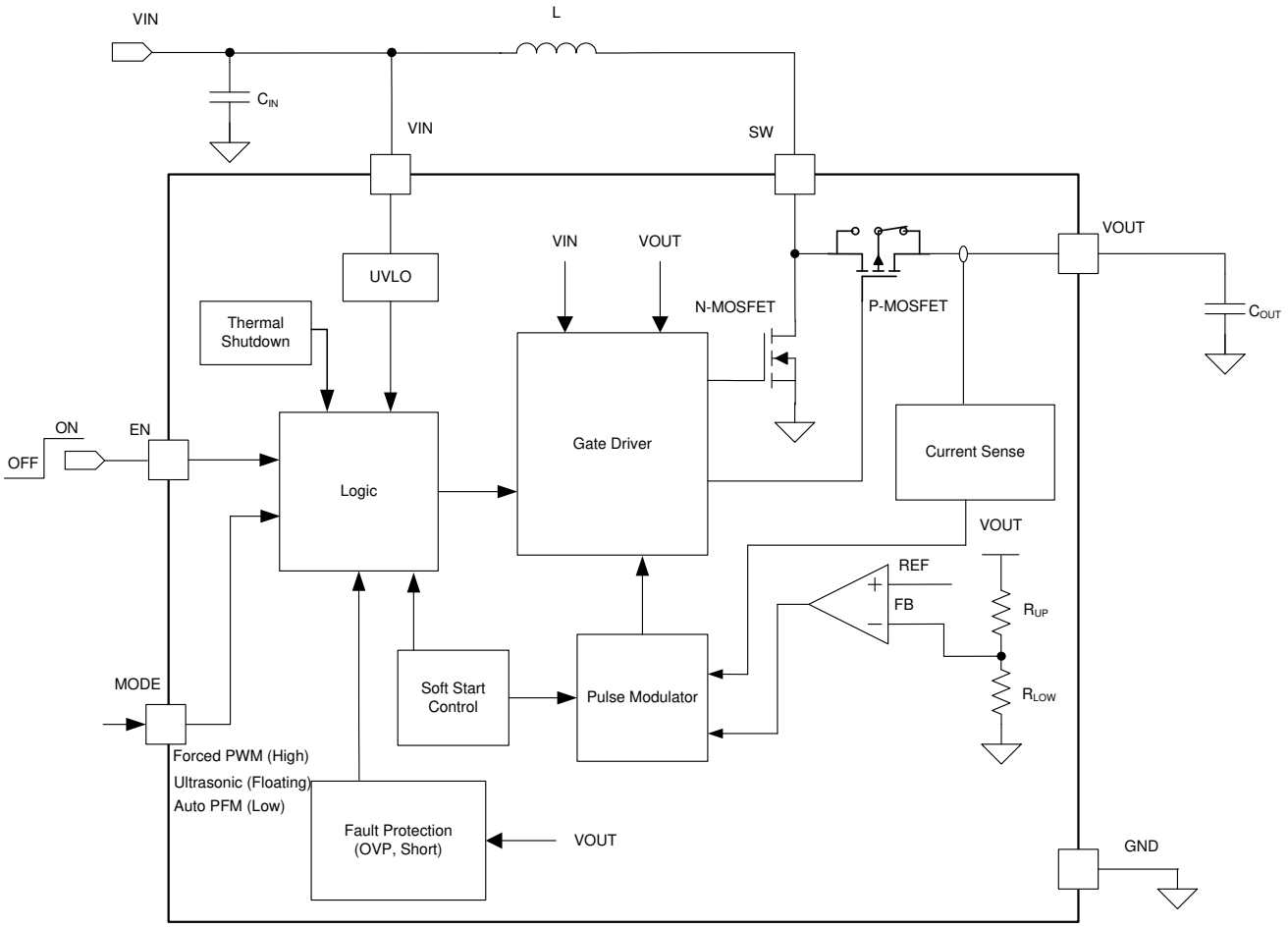
The TPS61253x synchronous step-up converter typically operates at a quasi-constant 3.8MHz frequency pulse width modulation (PWM) from the moderate-to-heavy load currents. During the PWM operation, the converter uses a quasi-constant on-time valley current mode control scheme to achieve the excellent line / load regulation and allows the use of a small inductor and ceramic capacitors. Based on the V_{IN} / V_{OUT} ratio, a simple circuit predicts the required on-time. At the beginning of the switching cycle, the low-side N-MOS switch is turned on and the inductor current ramps up to a peak current that is defined by the on-time and the inductance. In the second phase, once the on-timer has expired, the rectifier FET is turned on and the inductor current decays to a preset valley current threshold. Then, the switching cycle repeats by setting the on timer again and activating the low-side N-MOS switch.

At the light load current conditions, the TPS61253x can be flexibly configured at the Auto PFM mode, the forced PWM or the ultrasonic mode. At the Auto PFM mode, the TPS61253x converter operates in Power Save Mode with pulse frequency modulation (PFM) and improves the efficiency. For forced PWM mode, the switching frequency is the same at the light load as that of heavy load. The ultrasonic mode is a unique control feature that keeps the switching frequency above 25kHz to avoid the acoustic audible frequencies toward virtually no load condition.

In general, a dc/dc step-up converter can only operate in "true" boost mode, that is the output “boosted” by a certain amount above the input voltage. The TPS61253x device operates differently as it can smoothly transition in and out of pass-through operation (V_{IN} exceeds the preset out of Boost). Therefore the output can be kept as close as possible to its regulation limits even though the converter is subject to an input voltage that tends to be excessive.

Internal soft start and loop compensation simplify the design process while minimizing the number of external components.

7.2 Functional Block Diagram



7.3 Feature Description

7.3.1 Start-up

The TPS61253x integrates an internal circuit that controls the ramp up of the output voltage during start-up and prevents the converter from the large inrush current. When the device is enabled, the high-side rectifying switch turns on to charge the output capacitor linearly which is called the pre-charge phase. During the pre-charge phase, the output current is limited to the pre-charge current limit ILIM_DC. The pre-charge phase terminates when the output voltage getting close to the input voltage.

Once the output capacitor has been biased close to the input voltage, the device starts switching which is called the soft-start phase. During the soft start phase, a soft-start voltage is used to regulate the FB pin voltage, and the output voltage rising slope follows the soft-start voltage slope. The device successfully completes the soft-start phase and operates normally once the nominal output voltage is reached.

Table 7-1. Start-up Mode Description

MODE	DESCRIPTION	CONDITION
Pre-charge	V_{OUT} linearly starts up without switching	$V_{OUT} < V_{IN}$ - 300mV
Boost soft start	V_{OUT} starts up wih switching phrase	$V_{OUT\_BOOST} \geq V_{OUT} \geq V_{IN}$ - 300mV

7.3.2 Enable and Disable

The device is enabled by setting the EN pin to a voltage above 1.2V (TPS61253A) or 0.9V (TPS61253E and TPS61253F) and the V_{IN} above the UVLO threshold. At first, the internal reference is activated and the internal

analog circuits are settled. Afterwards, the start-up phase is activated and the output voltage increases. When the EN pin is grounded, the TPS61253x enters shutdown mode, then device stops switching and the internal control circuitry is turned off.

7.3.3 Undervoltage Lockout (UVLO)

The undervoltage lockout circuit prevents the device from malfunctioning when the battery voltage is too low due to excessive discharge. The device starts operation once the rising V_{IN} trips the undervoltage lockout (UVLO) threshold and it disables the output stage of the converter once the V_{IN} is below UVLO falling threshold.

7.3.4 Current Limit Operation

During the start-up phase, the output current is limited to the pre-charge current limit which is specified as the ILIM_DC in *Section 6.5*.

The TPS61253x employs a valley current sensing scheme during the normal boost switching phase. When the output load increases, the cycle-by-cycle valley current limit will be triggered. As shown in Figure 7-1, the maximum continuous output current before entering the current limit operation can be defined by Equation 1:

$$I_{OUT\_LIM} = (1 - D) \times (I_{VALLEY\_LIM} + \frac{1}{2}\Delta I_L) \quad (1)$$

$$D = 1 - \frac{V_{IN} \times \eta}{V_{OUT}} \quad (2)$$

$$\Delta I_L = \frac{V_{IN}}{L} \times \frac{D}{f} \quad (3)$$

where

- I_{OUT_LIM} is the output current limit, I_{VALLEY_LIM} is switching valley current limit
- Δ_{IL} is the peak-peak inductor current ripple
- D is the duty cycle, f is the switching frequency, η is the efficiency, L is the inductor
- V_{OUT} is the output voltage, V_{IN} is the input voltage

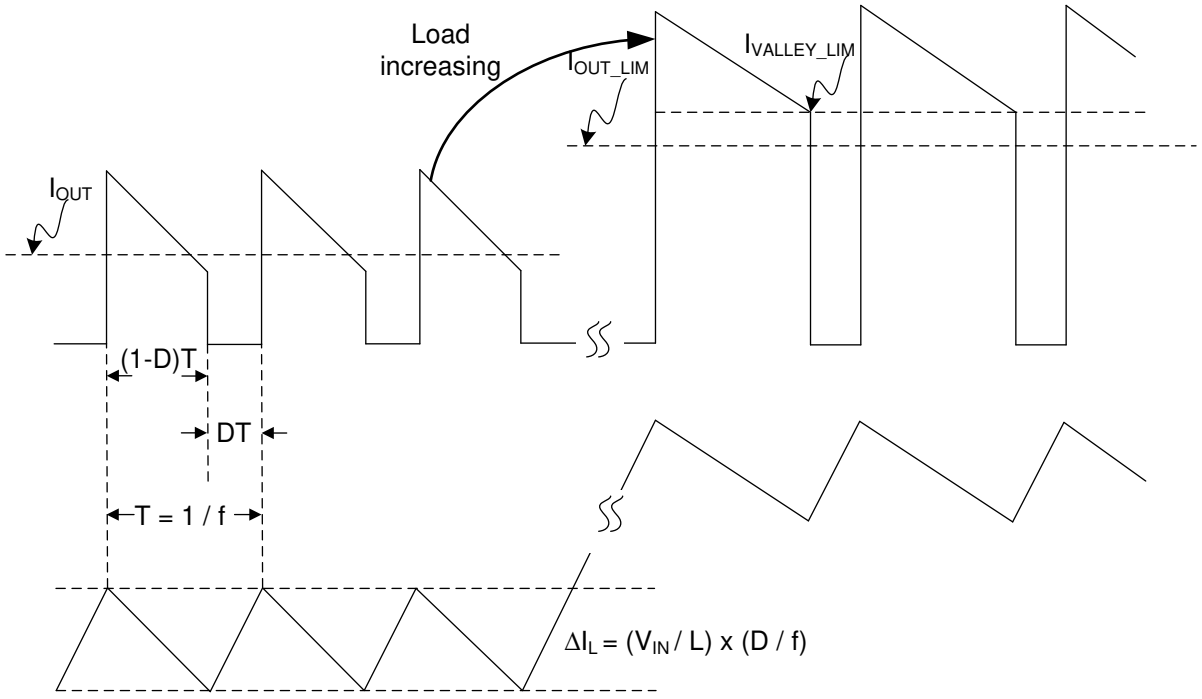


Figure 7-1. Current Limit Operation

If the output current is further increased and triggers the short protection threshold (typical 6A of inductor current), the TPS61253x enters hiccup mode. Once the hiccup is triggered, the device turns on the high-side FET for around 1ms with the pre-charge current limit and stops for around 20ms. The hiccup on / off cycle repeats again and again if the short condition is present. Figure 7-2 illustrates the TPS61253x working scheme of the hiccup mode. The average current and thermal will be much lowered at the hiccup steady state and the device can recover automatically as long as the short releases.

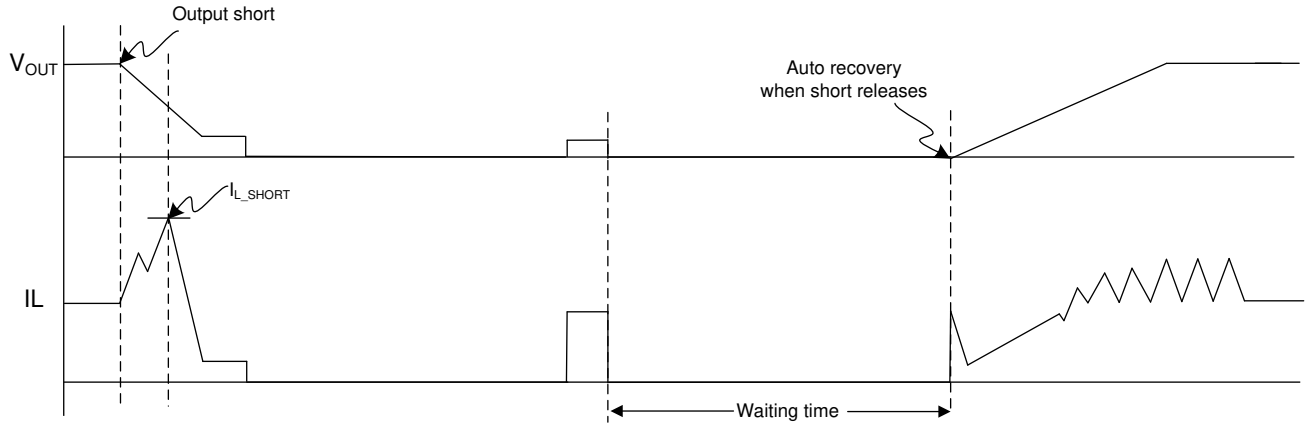


Figure 7-2. Hiccup Mode Short Protection

7.3.5 Load Disconnection

TPS61253x has load disconnection function. When the converter is disabled, it disconnects the output from the input of the power supply. If a battery is connected, this function also prevents the battery from discharging while the converter is off.

7.3.6 Thermal Shutdown

The TPS61253x has a built-in temperature sensor that monitors the internal junction temperature, T_J. If the junction temperature exceeds the threshold (typical 150°C), the device goes into thermal shutdown, and the

high-side and low-side FETs are turned off. When the junction temperature falls below the thermal shutdown falling threshold (typical 130°C), the device resumes the operation.

7.4 Device Functional Modes

7.4.1 Auto PFM Mode

The device integrates power save mode with pulse frequency modulation (Auto PFM) to improve the efficiency at the light load. At the light load operation, when the valley current of the inductor triggers the Auto PFM threshold, the device enters into Auto PFM mode operation. During the Auto PFM operation, the output voltage is regulated at typically 100.8% of voltage of the heavy load with the off-time extended to lower the switching frequency. The Auto PFM operation exists when valley current exceeds the Auto PFM threshold. Figure 7-3 shows the output voltage behavior of Auto PFM operation.

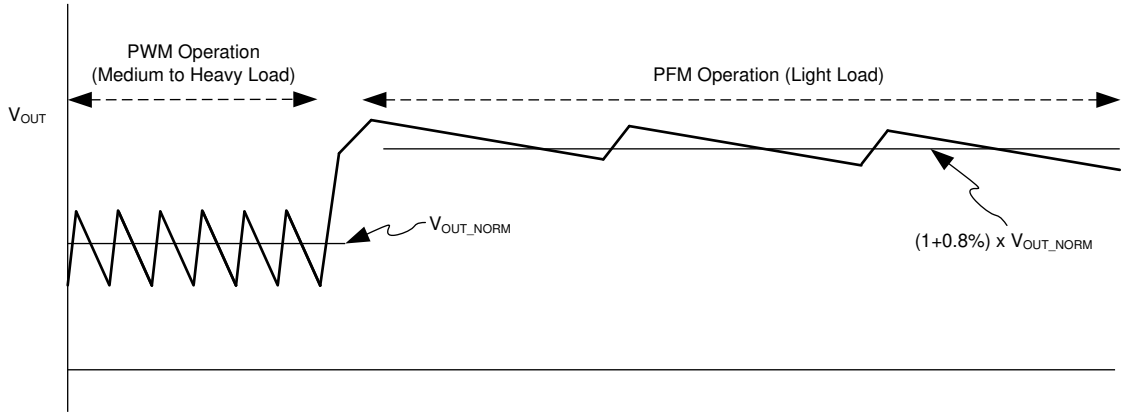


Figure 7-3. Output Voltage in Auto PFM / PWM Mode

7.4.2 Forced PWM Mode

In forced PWM mode, the TPS61253x keeps the switching frequency being constant for the whole load range. When the load current decreases, the output of the internal error amplifier decreases as well to lower the inductor peak current and delivers less power from input to output. The high-side FET is not turned off even if the current through the FET goes negative to keep the switching frequency being the same as that of the heavy load.

7.4.3 Ultrasonic Mode

The ultrasonic mode is an unique control feature that keeps the switching frequency above the acoustic audible frequency toward no load condition. The ultrasonic mode control circuit monitors the switching frequency and keeps the switching frequency above 25kHz to avoid the acoustic band. The output voltage becomes typically 1.6% higher than PWM operation. Figure 7-4 illustrates the details of ultrasonic mode operation.

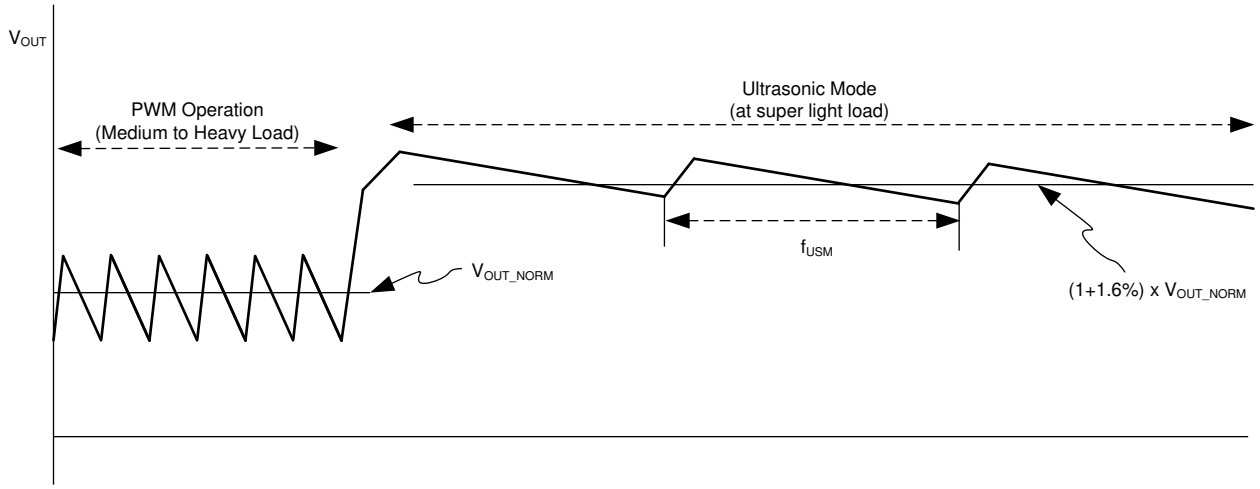


Figure 7-4. Ultrasonic Mode Operation

7.4.4 Pass-Through Mode

When the input voltage is higher than V_{OUT} + 0.1V and V_{OUT} is higher than the nominal output voltage, the device automatically enters pass-through mode. In pass-through mode, the high-side FET is fully turned on and the low-side switch is turned off. The output voltage follows the input with the drop caused by the inductor resistance and the high-side FET resistance.

8 Application and Implementation

Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

8.1 Application Information

With a wide input voltage range, the TPS61253x supports applications powered by Li-Ion batteries with extended voltage range. Intended for the low-power applications, it supports up to 1500mA load current from a battery discharged as low as 3V and allows the use of low cost chip inductor and capacitors. The TPS61253x offers a very small solution size due to minimum amount of external components. It allows the use of small inductors and input capacitors to achieve a small solution size. During the pass-through mode, the output voltage is biased to the input voltage.

8.2 Typical Application

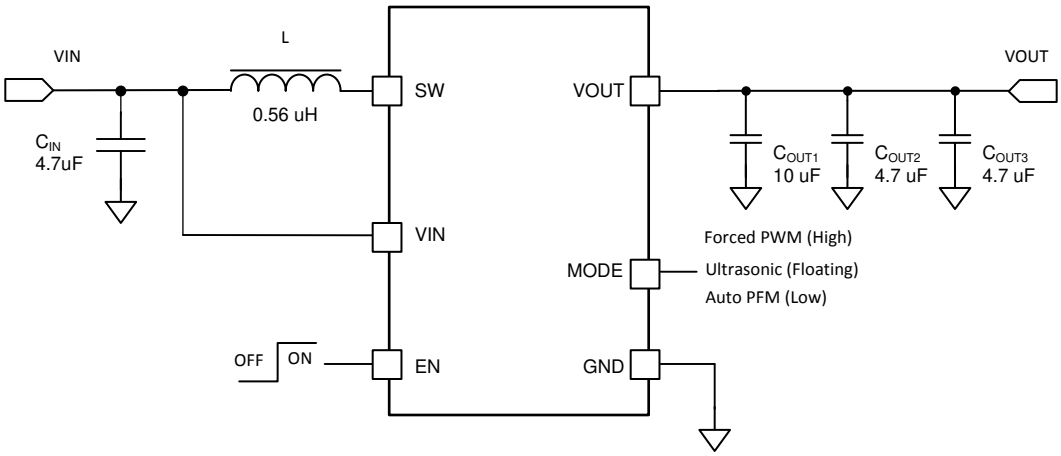


Figure 8-1. Typical Application Circuit

8.2.1 Design Requirements

In this example, TPS61253x is used to design a 5V output Boost converter. The TPS61253x can be powered by one-cell Li-ion battery. It supports up to 1500mA output current from the input voltage as low as 3V. During shutdown, the load is completely disconnected from the battery.

8.2.2 Detailed Design Procedure

8.2.2.1 Custom Design With WEBENCH® Tools

Click here to create a custom design using the TPS61253x device with the WEBENCH® Power Designer.

1. Start by entering the input voltage (V_{IN}), output voltage (V_{OUT}), and output current (I_{OUT}) requirements.
2. Optimize the design for key parameters such as efficiency, footprint, and cost using the optimizer dial.
3. Compare the generated design with other possible solutions from Texas Instruments.

The WEBENCH Power Designer provides a customized schematic along with a list of materials with real-time pricing and component availability.

In most cases, these actions are available:

- Run electrical simulations to see important waveforms and circuit performance
- Run thermal simulations to understand board thermal performance

- Export customized schematic and layout into popular CAD formats
- Print PDF reports for the design, and share the design with colleagues

Get more information about WEBENCH tools at www.ti.com/WEBENCH.

8.2.2.2 Inductor Selection

A boost converter normally requires two main passive components for storing energy during the conversion, an inductor and an output capacitor. It is advisable to select an inductor with a saturation current rating higher than the possible peak current flowing through the power switches.

The inductor peak current varies as a function of the load, the input and output voltages. It can be estimated using Equation 4.

$$I_{L(PEAK)} = \frac{V_{IN} \cdot D}{2 \cdot f \cdot L} + \frac{I_{OUT}}{(1-D)} \quad \text{with} \quad D = 1 - \frac{V_{IN} \cdot \eta}{V_{OUT}} \tag{4}$$

Selecting an inductor with insufficient saturation current can lead to excessive peak current in the converter. This could eventually harm the device and reduce its reliability. When selecting the inductor, as well as the inductance, parameters of importance are: the maximum current rating, series resistance, and operating temperature. The inductor DC current rating should be greater (by some margin) than the maximum input average current, refer to Equation 5 for more details.

$$I_{L(DC)} = \frac{V_{OUT}}{V_{IN}} \cdot \frac{1}{\eta} \cdot I_{OUT} \tag{5}$$

The TPS61253x series of step-up converters could support operating with an effective inductance in the range of 0.33µH to 1.3µH and with effective output capacitance in the range of 3.5µF to 30µF. The internal compensation is optimized for an output filter of the inductance between 0.56µH and 1µH and output capacitance from 5µF to10µF. Larger or smaller inductor and capacitor values can be used to optimize the performance of the device for specific operating conditions. For more details, see *Section 8.2.2.5*.

In high-frequency converter applications, the efficiency is essentially affected by the inductor AC resistance (that is, quality factor) and to a smaller extent by the inductor DCR value. To achieve high efficiency operation, care should be taken in selecting inductors featuring a quality factor above 25 at the switching frequency. Increasing the inductor value produces lower RMS current, but degrades transient response. For a given physical inductor size, increased inductance usually results in an inductor with lower saturation current.

The total losses of the coil consist of both the losses in the DC resistance, R(DC) , and the following frequency dependent components:

- The losses in the core material (magnetic hysteresis loss, especially at high switching frequencies)
- Additional losses in the conductor from the skin effect (current displacement at high frequencies)
- Magnetic field losses of the neighboring windings (proximity effect)
- Radiation losses

The following inductor series from different suppliers have been used with the TPS61253x converters.

Table 8-1. List of Inductors

MANUFACTURER(1)	SERIES	DESCRIPTION	DIMENSIONS (W × L × H)
Colicraft	XEL3515-561MEB	0.56µH, 21.5mΩ DCR, 6.5A I_{sat}	3.2mm × 3.5mm × 1.5mm
Murata	1277AS-H-1R0M=P2	1µH, 34mΩ DCR, 4.6A I_{sat}	3.2mm × 2.5mm × 1.2mm

(1) See *Section 9.1.1*.

8.2.2.3 Output Capacitor

For the output capacitor, it is recommended to use small ceramic capacitors placed as close as possible to the VOUT and GND pins of the IC. If, for any reason, the application requires the use of large capacitors which cannot be placed close to the IC, using a smaller ceramic capacitor in parallel to the large one is highly recommended. This small capacitor should be placed as close as possible to the VOUT and GND pins of the IC. To get an estimate of the recommended minimum output capacitance, Equation 6 can be used.

$$C_{MIN} = \frac{I_{OUT} \cdot (V_{OUT} - V_{IN})}{f \cdot \Delta V \cdot V_{OUT}} \quad (6)$$

where

- f is the switching frequency which is 3.8MHz (typ.)
- ΔV is the maximum allowed output ripple

With a chosen ripple voltage of 25mV, a minimum effective capacitance of 7µF is needed for maximum 1500mA load. The capacitor can be smaller if the load is lower or the ripple can be larger. The total ripple is larger due to the ESR of the output capacitor. This additional component of the ripple can be calculated using Equation 7

$$V_{ESR} = I_{OUT} \cdot R_{ESR} \quad (7)$$

An MLCC capacitor with twice the value of the calculated minimum should be used due to DC bias effects. This is required to maintain control loop stability. The output capacitor requires either an X7R or X5R dielectric. Y5V and Z5U dielectric capacitors, aside from their wide variation in capacitance over temperature, become resistive at high frequencies. There are no additional requirements regarding minimum ESR. Larger capacitors cause lower output voltage ripple as well as lower output voltage drop during load transients but the total effective output capacitance value should not exceed ca. 30µF.

DC bias effect: high cap. ceramic capacitors exhibit DC bias effects, which have a strong influence on the effective capacitance of the device. Therefore, the right capacitor value has to be chosen very carefully. Package size and voltage rating in combination with material are responsible for differences between the rated capacitor value and effective capacitance. For instance, a 10µF X5R 6.3V 0603 MLCC capacitor would typically show an effective capacitance of less than 4µF under 5V bias condition.

8.2.2.4 Input Capacitor

Multilayer ceramic capacitors are an excellent choice for input decoupling of the step-up converter since they have extremely low ESR and are available in small footprints. Input capacitors should be located as close as possible to the device. While a 4.7µF input capacitor is sufficient for most applications, larger values can be used to reduce input current ripple without limitations.

Take care when using only ceramic input capacitors. When a ceramic capacitor is used at the input and the power is being supplied through long wires, such as from a wall adapter, a load step at the output can induce ringing at the VIN pin. This ringing can couple to the output and be mistaken as loop instability or could even damage the part. Additional "bulk" capacitance (electrolytic or tantalum) should in this circumstance be placed between C_{IN} and the power source lead to reduce ringing that can occur between the inductance of the power source leads and C_{IN}.

8.2.2.5 Checking Loop Stability

The first step of circuit and stability evaluation is to look from a steady-state perspective at the following signals:

- Switching node, SW
- Inductor current, I_L
- Output ripple voltage, $V_{OUT(AC)}$

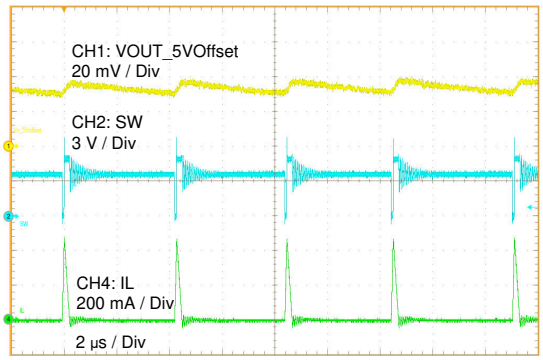
These are the basic signals that need to be measured when evaluating a switching converter. When the switching waveform shows large duty cycle jitter or the oscillation happens for the output voltage or inductor current, the regulation loop can be unstable. This is often a result of board layout, L-C combination, or both.

As a next step in the evaluation of the regulation loop, the load transient response is tested. The time between the application of the load transient and the turn on of the high-side FET, the output capacitor must supply all of the current required by the load. V_{OUT} immediately shifts by an amount equal to $\Delta I_{(LOAD)}$ × ESR, where ESR is the effective series resistance of C_{OUT}. $\Delta I_{(LOAD)}$ begins to charge or discharge C_{OUT} generating a feedback error signal used by the regulator to return V_{OUT} to its steady-state value. The results are most easily interpreted when the device operates in PWM mode.

During this recovery time, V_{OUT} can be monitored for settling time, overshoot, or ringing that helps judge the stability of the converter. Without any ringing, the loop has usually more than 45° of phase margin. Because the damping factor of the circuitry is directly related to several resistive parameters (for example, MOSFET $r_{DS(on)}$) that are temperature dependent, the loop stability analysis has to be done over the input voltage range, load current range, and temperature range.

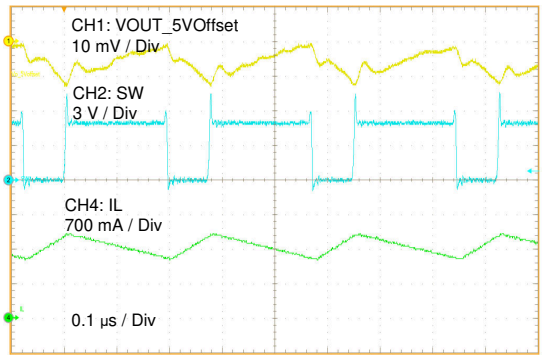
8.2.2.6 Application Curves

This section is based on the test results of TPS61253A, unless otherwise noted.



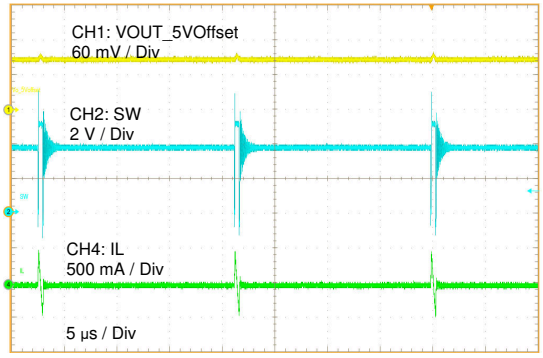
V_{IN} = 3.6V | V_{OUT} = 5A | L = 0.56µH
C_{OUT} = 10µF + 2x 4.7µF | Load = 10mA | Auto PFM

Figure 8-2. Steady 10mA



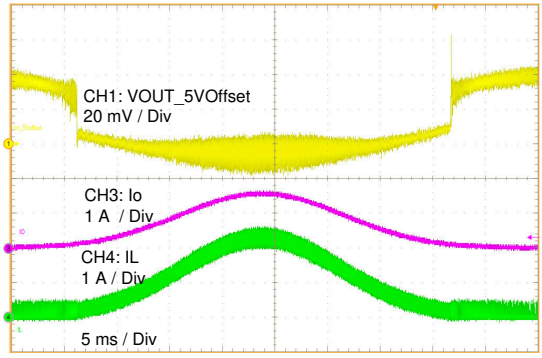
V_{IN} = 3.6V | V_{OUT} = 5A | L = 0.56µH
C_{OUT} = 10µF + 2x 4.7µF | Load = 1000mA | Auto PFM

Figure 8-3. Steady 1000mA



V_{IN} = 3.6V | V_{OUT} = 5A | L = 0.56µH
C_{OUT} = 10µF + 2x 4.7µF | Load = 0mA | Auto PFM

Figure 8-4. Steady Ultrasonic Mode

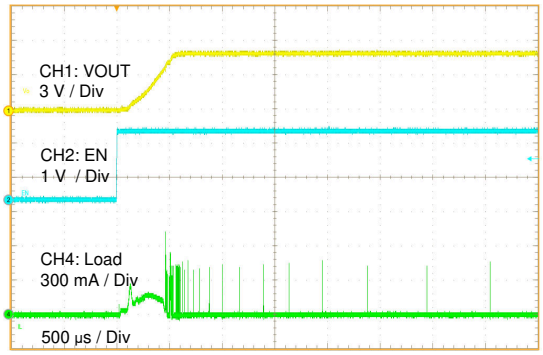


V_{IN} = 3.6V | V_{OUT} = 5A | L = 0.56µH
C_{OUT} = 10µF + 2x 4.7µF | Auto PFM

Figure 8-5. Load Sweep

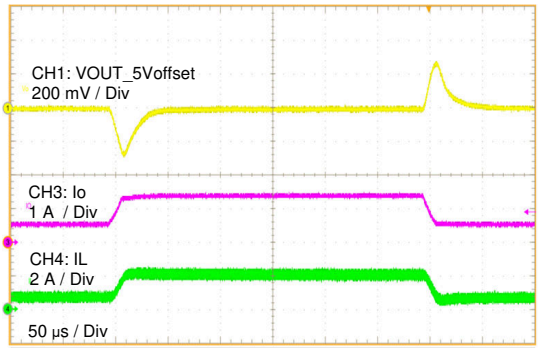
8.2.2.6 Application Curves (continued)

This section is based on the test results of TPS61253A, unless otherwise noted.



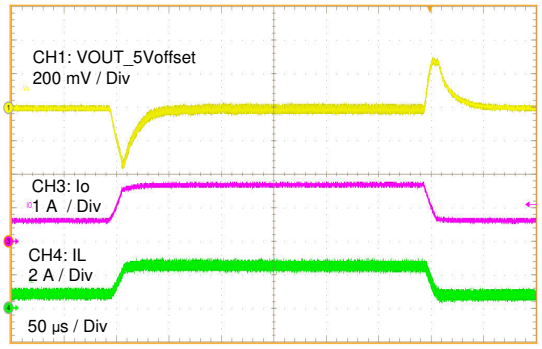
V_{IN} = 3.6V
C_{OUT} = 10µF + 2x 4.7µF
V_{OUT} = 5A
Load = 0mA
L = 0.56µH
Auto PFM

Figure 8-6. Start-up by EN



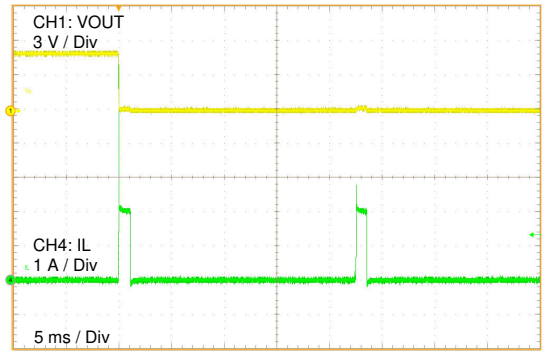
V_{IN} = 3.6V
C_{OUT} = 10µF + 2x4.7µF
V_{OUT} = 5V
Load = 0.5A to 1A, 20µs/A
L = 0.56µH
Auto PFM

Figure 8-7. Load Transient



V_{IN} = 3.6V
C_{OUT} = 10µF
V_{OUT} = 5V
Load = 0.5A to 1A, 20µs/A
L = 0.56µH
Auto PFM

Figure 8-8. Load Transient with 10µF C_{OUT}



V_{IN} = 3.6V
C_{OUT} = 10µF + 2x4.7µF
V_{OUT} = 5V
Auto PFM
L = 0.56µH

Figure 8-9. Short Output

8.2.3 System Examples

For the < 1000mA output current application, the output capacitors could be less. Figure 8-10 shows the typical application circuit for the lower current applications.

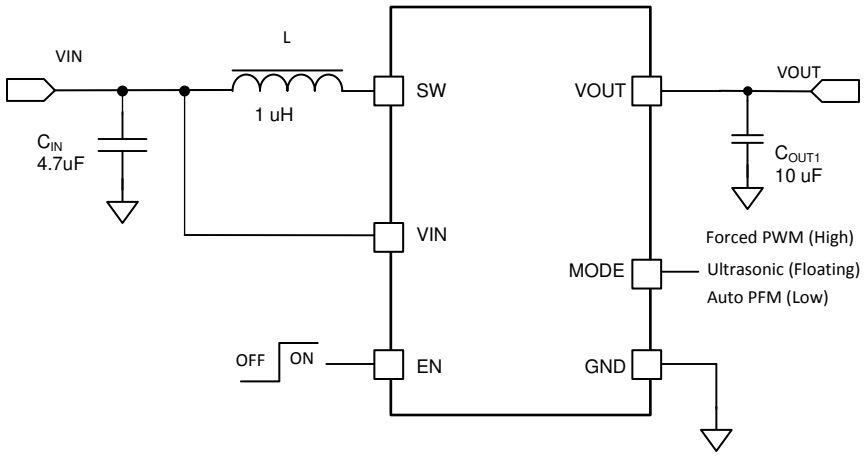


Figure 8-10. Typical Application with Minimum Output Capacitance

8.3 Power Supply Recommendations

The power supply can be three-cell alkaline, NiCd or NiMH, or one-cell Li-Ion or Li-Polymer battery. The input supply should be well regulated with the rating of TPS61253x. If the input supply is located more than a few inches from the device, additional bulk capacitance may be required in addition to the ceramic bypass capacitors. An electrolytic or tantalum capacitor with a value of 47µF is a typical choice.

8.4 Layout

8.4.1 Layout Guidelines

For all switching power supplies, the layout is an important step in the design, especially at high peak currents and high switching frequencies. If the layout is not carefully done, the regulator can show stability problems as well as EMI problems. Therefore, use wide and short traces for the main current path and for the power ground tracks. The input capacitor, output capacitor, and the inductor should be placed as close as possible to the IC. Use a common ground node for power ground and a different one for control ground to minimize the effects of ground noise. Connect these ground nodes at any place close to the ground pins of the IC.

8.4.2 Layout Example

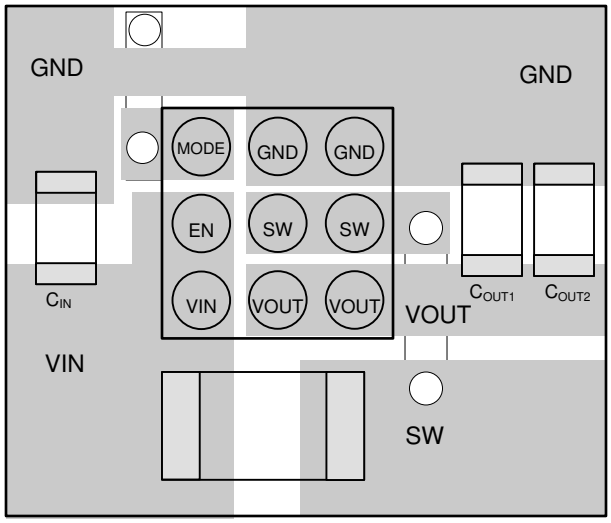


Figure 8-11. Recommended Layout

8.4.3 Thermal Considerations

Implementation of integrated circuits in low-profile and fine-pitch surface-mount packages typically requires special attention to power dissipation. Many system-dependent issues such as thermal coupling, airflow, added heat sinks and convection surfaces, and the presence of other heat-generating components affect the power-dissipation limits of a given component.

The following are three basic approaches for enhancing thermal performance:

- Improving the power dissipation capability of the PCB design
- Improving the thermal coupling of the component to the PCB
- Introducing airflow in the system

As power demand in portable designs is more and more important, designers must figure the best trade-off between efficiency, power dissipation and solution size. Due to integration and miniaturization, junction temperature can increase significantly which could lead to bad application behaviors (that is, premature thermal shutdown or worst case reduce device reliability).

Junction-to-ambient thermal resistance is highly dependent on application and board-layout. In applications where high maximum power dissipation exists, special care must be paid to thermal dissipation issues in board design. The device operating junction temperature (T_J) should be kept below 125°C.

9 Device and Documentation Support

9.1 Device Support

9.1.1 Third-Party Products Disclaimer

TI'S PUBLICATION OF INFORMATION REGARDING THIRD-PARTY PRODUCTS OR SERVICES DOES NOT CONSTITUTE AN ENDORSEMENT REGARDING THE SUITABILITY OF SUCH PRODUCTS OR SERVICES OR A WARRANTY, REPRESENTATION OR ENDORSEMENT OF SUCH PRODUCTS OR SERVICES, EITHER ALONE OR IN COMBINATION WITH ANY TI PRODUCT OR SERVICE.

9.1.2 Development Support

9.1.2.1 Custom Design With WEBENCH® Tools

Click here to create a custom design using the TPS61253x device with the WEBENCH® Power Designer.

1. Start by entering the input voltage (V_{IN}), output voltage (V_{OUT}), and output current (I_{OUT}) requirements.
2. Optimize the design for key parameters such as efficiency, footprint, and cost using the optimizer dial.
3. Compare the generated design with other possible solutions from Texas Instruments.

The WEBENCH Power Designer provides a customized schematic along with a list of materials with real-time pricing and component availability.

In most cases, these actions are available:

- Run electrical simulations to see important waveforms and circuit performance
- Run thermal simulations to understand board thermal performance
- Export customized schematic and layout into popular CAD formats
- Print PDF reports for the design, and share the design with colleagues

Get more information about WEBENCH tools at www.ti.com/WEBENCH.

9.2 Documentation Support

9.2.1 Related Documentation

For related documentation see the following:

TPS61253AEVM-803 User's Guide, SLVUAP5

9.3 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Notifications* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

9.4 Support Resources

TI E2E™ support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

9.5 Trademarks

TI E2E™ is a trademark of Texas Instruments.
All trademarks are the property of their respective owners.

9.6 Electrostatic Discharge Caution

This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

9.7 Glossary

TI Glossary This glossary lists and explains terms, acronyms, and definitions.

10 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision E (June 2023) to Revision F (January 2026)	Page
• Added TPS61253F device	1
• Added explanation of the differences between TPS61253F, TPS61253A, TPS61253E and TPS612532A	1

Changes from Revision D (January 2021) to Revision E (June 2023)	Page
• TPS61253E initial release	1

Changes from Revision C (November 2020) to Revision D (January 2021)	Page
• Adding HS FET to the functional block diagram	12

11 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package | Pins	Package qty | Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
TPS612532AYFFR	Active	Production	DSBGA (YFF) | 9	3000 | LARGE T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 125	2CHI
TPS612532AYFFR.A	Active	Production	DSBGA (YFF) | 9	3000 | LARGE T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 125	2CHI
TPS61253AYFFR	Active	Production	DSBGA (YFF) | 9	3000 | LARGE T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 85	17NI
TPS61253AYFFR.A	Active	Production	DSBGA (YFF) | 9	3000 | LARGE T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 125	17NI
TPS61253AYFFT	Active	Production	DSBGA (YFF) | 9	250 | SMALL T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 85	17NI
TPS61253AYFFT.A	Active	Production	DSBGA (YFF) | 9	250 | SMALL T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 125	17NI
TPS61253EYFFR	Active	Production	DSBGA (YFF) | 9	3000 | LARGE T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 125	32UH
TPS61253EYFFR.A	Active	Production	DSBGA (YFF) | 9	3000 | LARGE T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 125	32UH
TPS61253FYFFR	Active	Production	DSBGA (YFF) | 9	3000 | LARGE T&R	-	SNAGCU	Level-1-260C-UNLIM	-40 to 125	3ZQH

(1) **Status:** For more details on status, see our product life cycle.

(2) **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

(3) **RoHS values:** Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

(4) **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

(5) **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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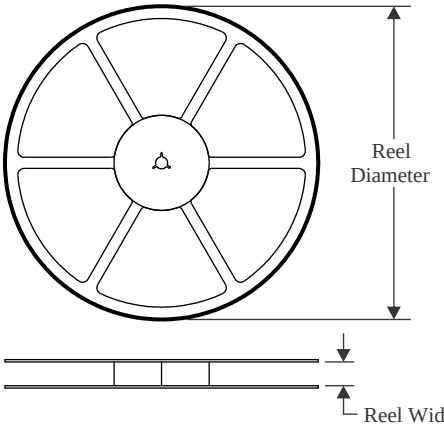
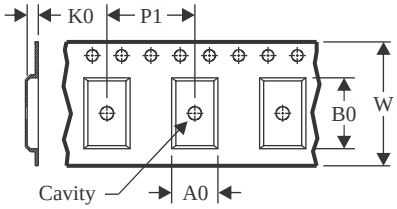
TAPE AND REEL INFORMATION

REEL DIMENSIONS

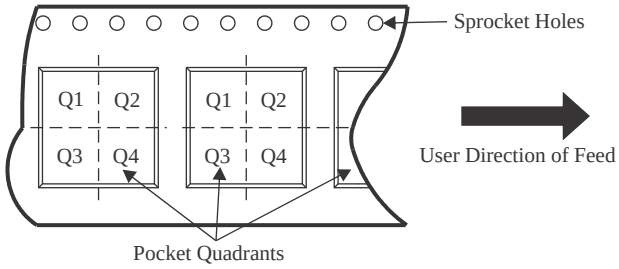


TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

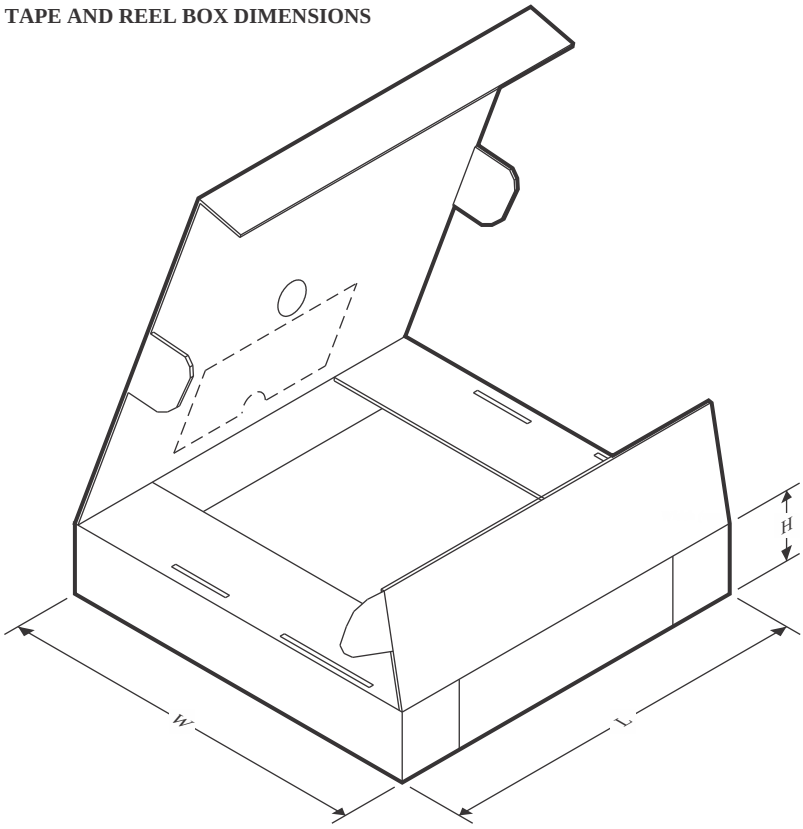
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPS612532AYFFR	DSBGA	YFF	9	3000	180.0	8.4	1.31	1.41	0.69	4.0	8.0	Q1
TPS61253AYFFR	DSBGA	YFF	9	3000	180.0	8.4	1.31	1.41	0.69	4.0	8.0	Q1
TPS61253AYFFT	DSBGA	YFF	9	250	180.0	8.4	1.31	1.41	0.69	4.0	8.0	Q1
TPS61253EYFFR	DSBGA	YFF	9	3000	180.0	8.4	1.31	1.41	0.69	4.0	8.0	Q1
TPS61253FYFFR	DSBGA	YFF	9	3000	180.0	8.4	1.31	1.41	0.69	4.0	8.0	Q1

TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

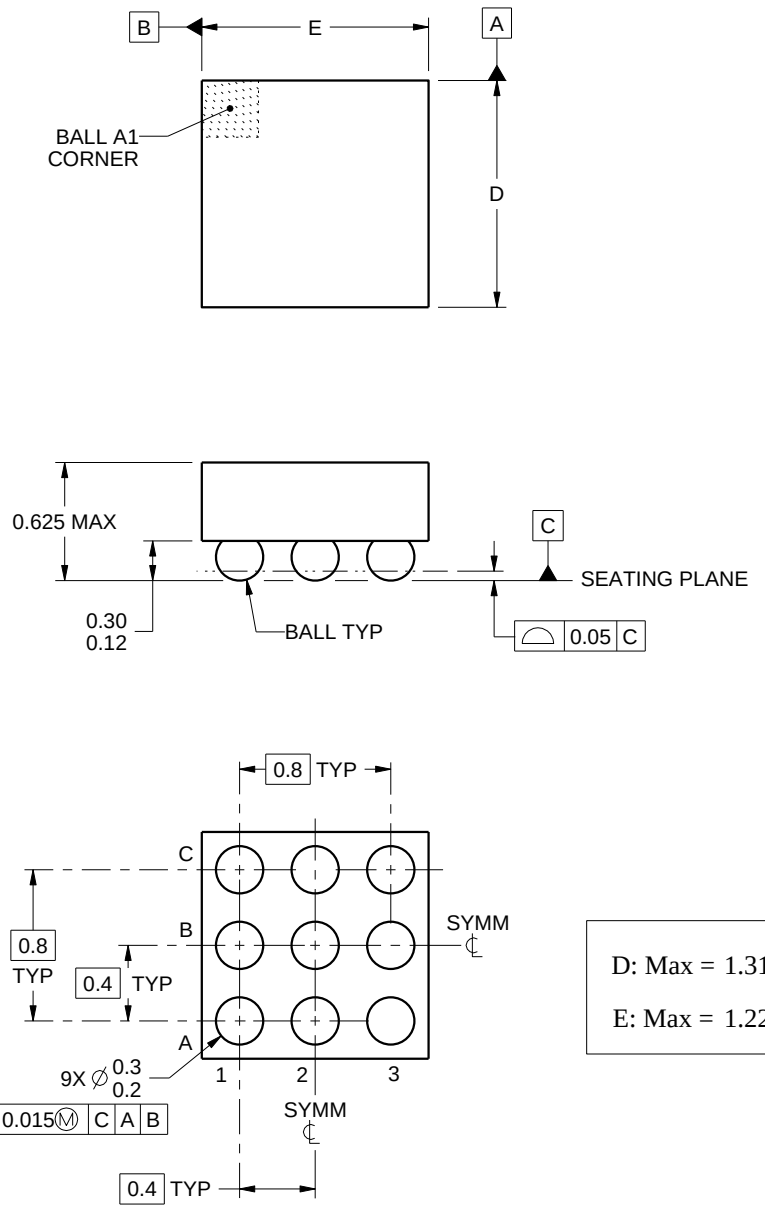
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPS612532AYFFR	DSBGA	YFF	9	3000	182.0	182.0	20.0
TPS61253AYFFR	DSBGA	YFF	9	3000	182.0	182.0	20.0
TPS61253AYFFT	DSBGA	YFF	9	250	182.0	182.0	20.0
TPS61253EYFFR	DSBGA	YFF	9	3000	182.0	182.0	20.0
TPS61253FYFFR	DSBGA	YFF	9	3000	182.0	182.0	20.0

PACKAGE OUTLINE

YFF0009

DSBGA - 0.625 mm max height

DIE SIZE BALL GRID ARRAY



D: Max = 1.318 mm, Min =1.258 mm

E: Max = 1.222 mm, Min =1.162 mm

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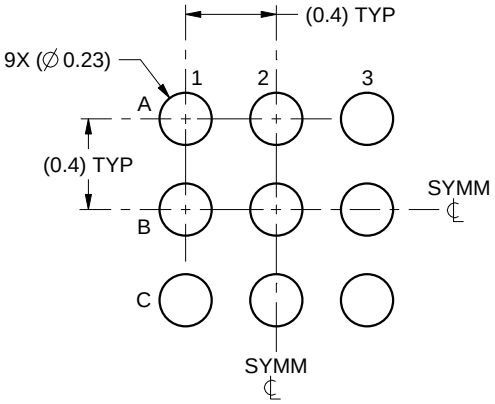
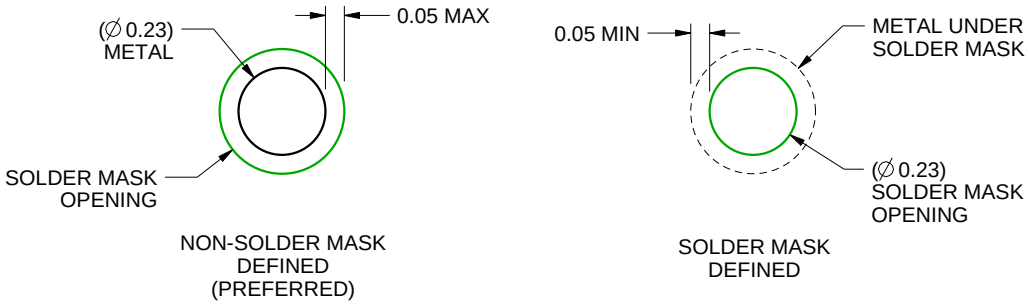
NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.



LAND PATTERN EXAMPLE
SCALE:30X



SOLDER MASK DETAILS
NOT TO SCALE

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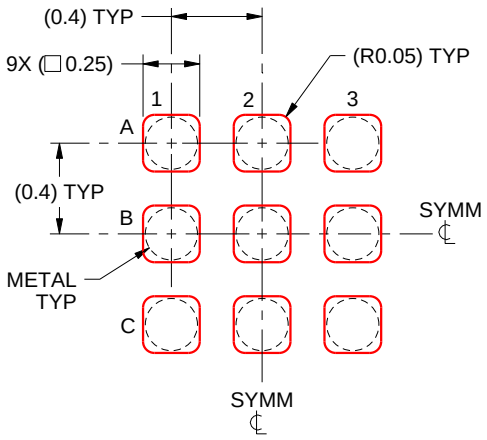
NOTES: (continued)

3. Final dimensions may vary due to manufacturing tolerance considerations and also routing constraints. For more information, see Texas Instruments literature number SNVA009 (www.ti.com/lit/snva009).



SOLDER PASTE EXAMPLE
BASED ON 0.1 mm THICK STENCIL
SCALE:30X

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NOTES: (continued)

4. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release.

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